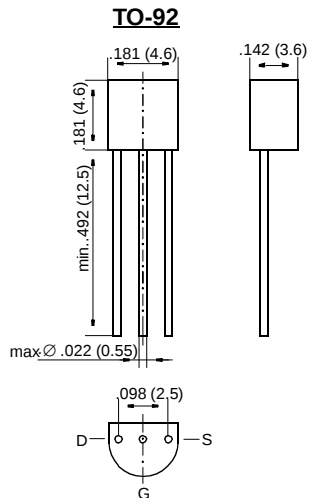


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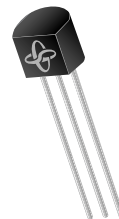
DMOS Transistors (N-Channel)



Dimensions in inches and (millimeters)

FEATURES

- ◆ High input impedance
- ◆ Low gate threshold voltage
- ◆ Low drain-source ON resistance
- ◆ High-speed switching
- ◆ No minority carrier storage time
- ◆ CMOS logic compatible input
- ◆ No thermal runaway
- ◆ No secondary breakdown



MECHANICAL DATA

Case: TO-92 Plastic Package

Weight: approx. 0.18 g

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25 °C ambient temperature unless otherwise specified

	Symbol	Value	Unit
Drain-Source Voltage	V_{DSS}	60	V
Drain-Gate Voltage	V_{DGS}	60	V
Gate-Source Voltage (pulsed)	V_{GS}	± 20	V
Drain Current (continuous) at $T_{amb}^{1)} = 25\text{ }^{\circ}\text{C}$, at $T_{SB}^{2)} = 50\text{ }^{\circ}\text{C}$	I_D	1.1	A
Power Dissipation at $T_{amb}^{1)} = 25\text{ }^{\circ}\text{C}$, at $T_{SB}^{2)} = 50\text{ }^{\circ}\text{C}$	P_{tot}	830 ¹⁾	mW
Junction Temperature	T_j	150	$^{\circ}\text{C}$
Storage Temperature Range	T_S	-65 to +150	$^{\circ}\text{C}$

¹⁾ Valid provided that leads are kept at ambient temperature at a distance of 2 mm from case (for TO-92).

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ELECTRICAL CHARACTERISTICS

Ratings at 25 °C ambient temperature unless otherwise specified

	Symbol	Min.	Typ.	Max.	Unit
Drain-Source Breakdown Voltage at $I_D = 100 \mu A$, $V_{GS} = 0 V$	$V_{(BR)DSS}$	60	80	—	V
Gate-Body Leakage Current, Forward at $V_{GSF} = 20 V$, $V_{DS} = 0 V$	I_{GSSF}	—	—	500	nA
Gate-Body Leakage Current, Reverse at $V_{GSR} = 20 V$, $V_{DS} = 0 V$	I_{GSSR}	—	—	500	nA
Drain Cutoff Current at $V_{DS} = 60 V$, $V_{GS} = 0 V$	I_{DSS}	—	—	250	μA
Gate-Source Threshold Voltage at $V_{GS} = V_{DS}$, $I_D = 250 \mu A$	$V_{GS(th)}$	1	1.5	3	V
Drain-Source ON Resistance at $V_{GS} = 10 V$, $I_D = 600 mA$	$R_{DS(on)}$	—	0.3	0.4	Ω
Capacitance at $V_{DS} = 25 V$, $V_{GS} = 0 V$, $f = 1 MHz$ Input Capacitance Output Capacitance Feedback Capacitance	C_{iSS} C_{oSS} C_{rSS}	— — —	350 150 35	— — —	pF pF pF
Switching Times at $V_{GS} = 10 V$, $V_{DS} = 10 V$, $R_D = 100 \Omega$ Turn-On Time Turn-Off Time	t_{on} t_{off}	— —	40 100	— —	ns ns
Thermal Resistance Junction to Ambient Air	R_{thJA}	—	—	150 ¹⁾	K/W
¹⁾ Valid provided that leads are kept at ambient temperature at a distance of 2 mm from case (for TO-92).					

Inverse Diode

	Symbol	Value	Unit
Max. Forward Current (continuous) at $T_{amb} = 25 ^\circ C$	I_F	1.1	A
Forward Voltage Drop (typ.) at $V_{GS} = 0 V$, $I_F = 1.1 A$, $T_j = 25 ^\circ C$	V_F	1	V